#### DB2G32600L1

#### For rectification

#### ■ Features

- Low forward voltage VF
- Forward current (Average) IF(AV) ≦ 1.0 A rectification is possible
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)

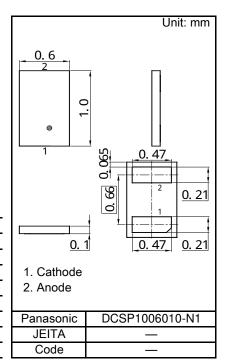
■ Marking Symbol: A4

#### Packaging

Embossed type (Thermo-compression sealing): 1 000 pcs / reel (standard)

#### ■ Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Reverse Voltage *1	VR	-	30	V
Maximum Peak Reverse Voltage *1	VRM	-	30	V
Average Forward Current *2,3	IF(AV)	-	1.0	Α
Average Forward Current *2,4	IF(AV)	-	1.0	Α
Non-repetitive Peak Surge Forward Current *1,5	IFSM	-	15	Α
Operating Junction Temperature *6	Tj	-	150	°C
Ambient Temperature	Та	-40	+150	°C
Storage Temperature	Tstg	-55	+150	°C



Note) \*1: Ta = Tj = 25°C

Revised

\*2: Squre wave :  $\sigma$  = 0.5

\*3: Ta ≦ 102°C, when device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36μm thick).

- \*4: Tsp ≦ 139°C
- \*5: Squre wave : Tp = 5 ms
- \*6: Power derating is necessary so that Tj < 150°C.

(Waveform definition)	IF <b>↑</b> ← Tp
Duty Cycle : $\sigma = \frac{Tp}{T}$	Time
	Time

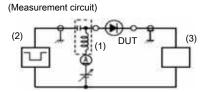
#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward Voltage	VF	IF = 1.0 A	-	0.35	0.44	V
Reverse Current	IR	VR = 30 V	-	200	900	μA
Terminal Capacitance	Ct	VR = 10 V, f = 1 MHz	-	32	-	pF
Reverse Recovery Time *1	trr	IF = IR = 100 mA, Irr = 10 mA	-	10	-	ns

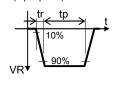
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.).

Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. \*1: Measurement circuit, input pulse, output pulse for Reverse recovery time



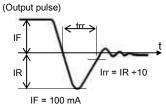
- (1) Bias Insertion Unit (N-50BU)
- (2) Pulse Generator (PG-10N), RS =  $50 \Omega$
- (3) Wave Form Analyzer (SAS-8130), Ri = 50  $\Omega$



(Input pulse)

tp = 2 ustr = 0.35 ns

 $\sigma = 0.05$ 

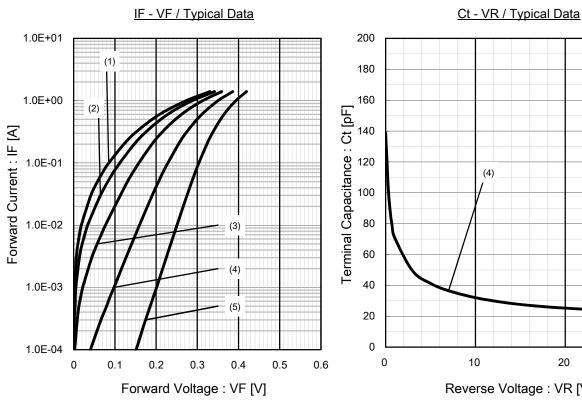


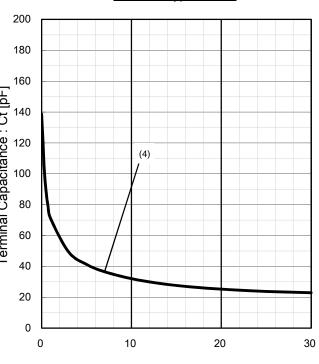
IR = 100 mA

Irr = 10 mA

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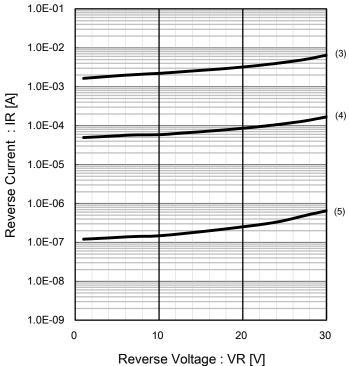
## Electrical Characteristics Technical Data (Reference)





Reverse Voltage: VR [V]

IR - VR / Typical Data



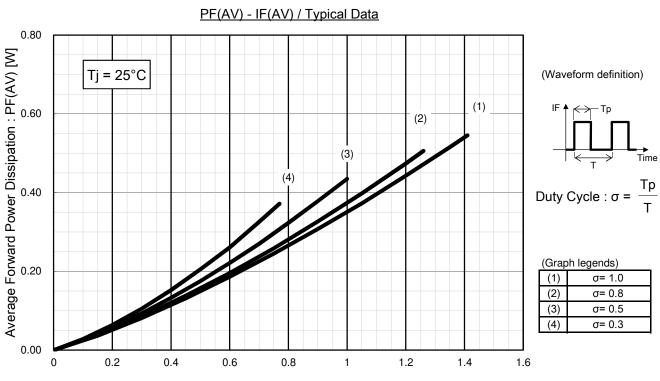
(Graph legends)				
(1)	Ta =	150	°C	
(2)	Ta =	125	°C	
(3)	Ta =	85	°C	
(4)	Ta =	25	°C	
(5)	Ta =	-40	°C	

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DB2G32600L1

# **Panasonic**

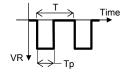
## Electrical Characteristics Technical Data (Reference)



Average Forward Current : IF(AV) [A]

# 0.0080 Tj = 25°C Tj = 25°C (1) (1) (2) (3) (4) (4)

(Waveform definition)



Duty Cycle :  $\sigma = \frac{Tp}{T}$ 

(Graph legends)

(Grapiriogoriae)			
(1)	σ= 1.0		
(2)	σ= 0.7		
(3)	σ= 0.5		
(4)	σ= 0.2		

Reverse Voltage: VR [V]

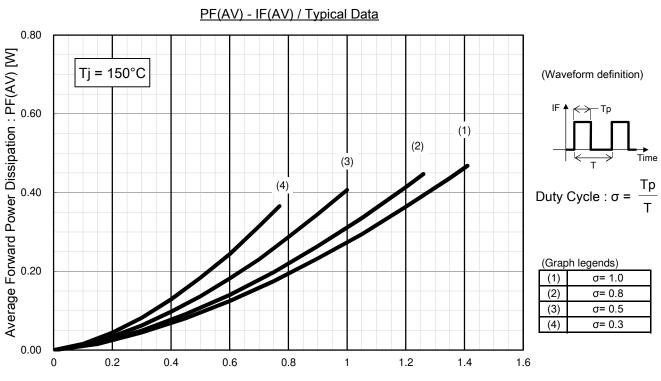
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DB2G32600L1

# **Panasonic**

## Electrical Characteristics Technical Data (Reference)



Average Forward Current : IF(AV) [A]

#### PR(AV) - VR / Typical Data 0.30 Average Reverse Power Dissipation: PR(AV) [W] Tj = 85°C (Waveform definition) 0.20 (1) Duty Cycle : $\sigma = \frac{Tp}{T}$ (2) 0.10 (3) (Graph legends) σ= 1.0 σ= 0.7 (4) σ= 0.5 (3) (4) $\sigma$ = 0.2 0.00 10 30 0

Reverse Voltage: VR [V]

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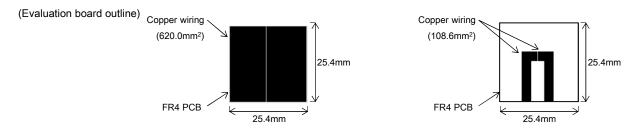
#### DB2G32600L1

# **Panasonic**

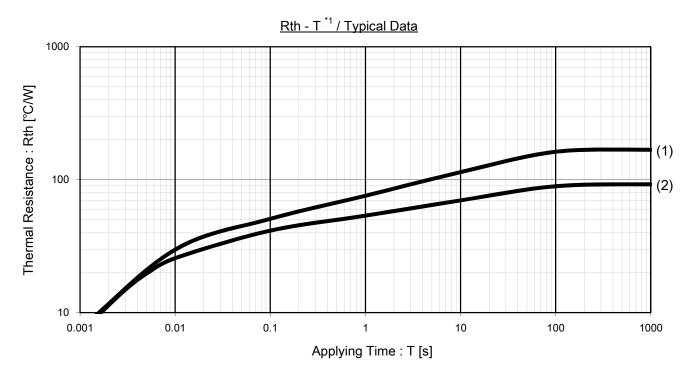
#### ■ Thermal Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Thermal Resistance, Junction to Solder Point	$R_{th(j-sp)}$	Ta = 25°C, in free air	-	20	1	°C/W
Thermal Resistance, Junction to Ambient *1	R <sub>th(j-a)</sub>	Ta = 25°C, in free air	-	92	-	°C/W
Thermal Resistance, Junction to Ambient *2	R <sub>th(j-a)</sub>	Ta = 25°C, in free air	-	170	-	°C/W

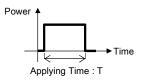
- Note) \*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).
  - \*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick).



#### Thermal Characteristics Technical Data (Reference)



Note) \*1: Single pulse measurement (Waveform definition)

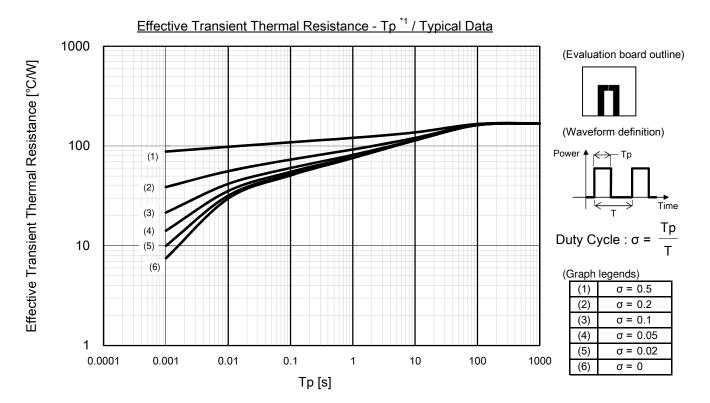


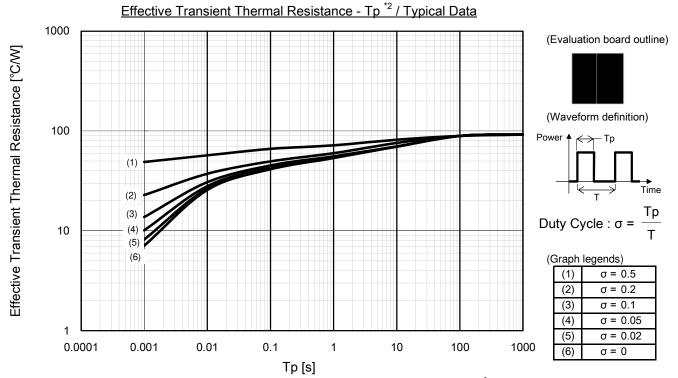
(Graph legends)

(1)		Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick),
		copper wiring (108.6mm <sup>2</sup> area, 36µm thick).
(2)		Device mounted on a FR4 PCB (25.4mm, 1mm thick),
(2)	copper wiring (620.0mm <sup>2</sup> area, 36µm thick).	

#### DB2G32600L1

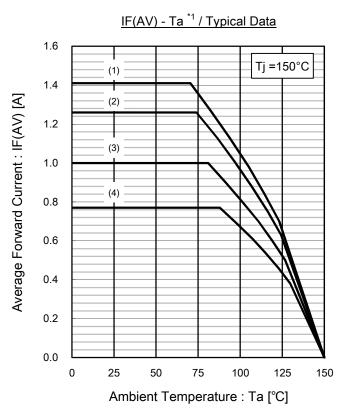
## Thermal Characteristics Technical Data (Reference)





Note) \*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick). \*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).

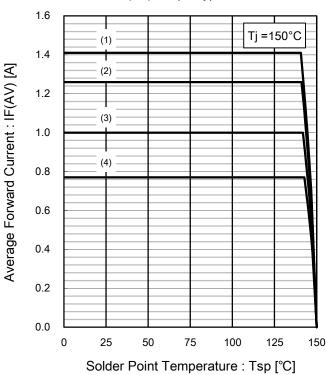
## Power Derating Technical Data (Reference)



1.6 Tj =150°C (1) 1.4 Average Forward Current: IF(AV) [A] (2) 1.2 (3) 1.0 (4) 8.0 0.6 0.4 0.2 0.0 25 50 75 150 100 125 Ambient Temperature : Ta [°C]

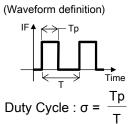
IF(AV) - Ta \*2 / Typical Data

IF(AV) - Tsp / Typical Data



(Graph legends)			
(1)	σ = 1.0		
(2)	$\sigma = 0.8$		
(3)	$\sigma = 0.5$		

 $\sigma = 0.3$ 



Note)

(4)

\*1: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (108.6mm² area, 36µm thick).

(Evaluation board outline)



\*2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (620.0mm² area, 36µm thick).

(Evaluation board outline)



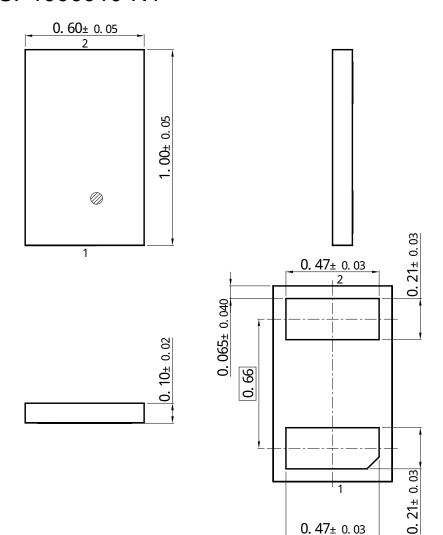
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Schottky Barrier Diode

### DB2G32600L1

## DCSP1006010-N1

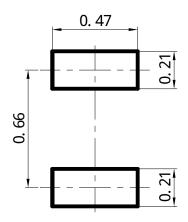
Unit: mm



■ Land Pattern (Reference)

Unit: mm

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